



INFRARED EMITTING DIODE

General Description

The OSE-1ML2 is a high power GaAs IRED mounted in TO-18 type header with clear epoxy encapsulation.

Features

- Low profile package
- Low cost
- High output power
- Meet RoHS

Applications

- Optical emitters
- Optical readers
- Encoders



MAXIMUM RATINGS

(Ta=25°C)

| Item | Symbol | Rating | Unit |
|--------------------------|--------|------------|----------------------|
| Reverse voltage | VR | 5 | V |
| Forward direct current | lF | 100 | mA |
| Power dissipation | Pb | 170 | mW |
| Pulse forward current *1 | IFP | 1 | Α |
| Operating temp. | Topr. | -25 ~ +100 | °C |
| Storage temp. | Tstg. | -25 ~ +100 | $^{\circ}\mathbb{C}$ |

^{*1} tw=100us, T=10ms

ELECTRO-OPTICAL CHARACTERISTICS

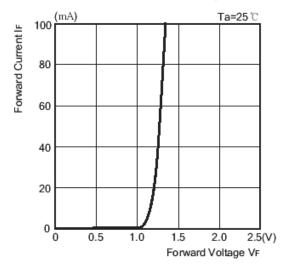
(Ta=25°C)

| Item | Symbol | Conditions | Min. | Тур. | Max. | Unit |
|---------------------------|--------|------------|------|------|------|-------|
| Radiant intensity | Po | IF=50mA | - | 2.7 | - | mW/sr |
| Forward voltage | VF | IF=50mA | - | 1.2 | 1.5 | V |
| Reverse current | IR | VR=5V | - | - | 10 | uA |
| Capacitance | Ct | f=1MHz | - | 25 | - | pF |
| Peak wavelength | λp | IF=50mA | - | 940 | - | nm |
| Spectral band width @ 50% | Δλ | IF=50mA | - | 50 | - | nm |
| Half angle | Δθ | IF=50mA | - | ±32 | - | deg. |

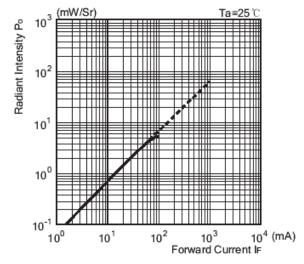




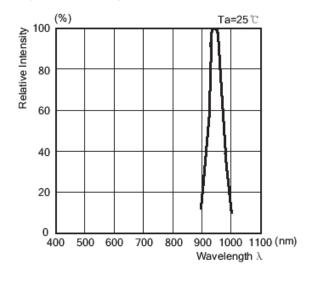
Forward Current / Forward Voltage IF/VF



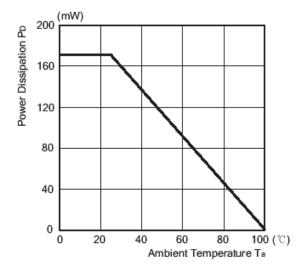
Radiant Intensity / Forward Current Po/IF



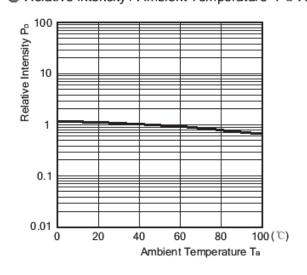
Spectral Intensity



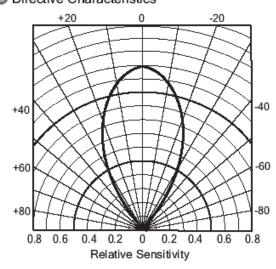
Power Dissipation / Ambient Temperature PD/Ta



Relative Intensity / Ambient Temperature P₀/Ta



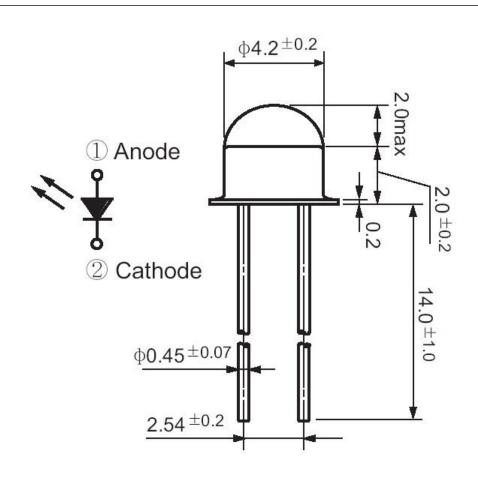
Directive Characteristics

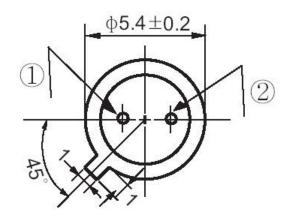






DIMEMSIONS





NOTES:

- 1. All dimensions are in millimeters.
- 2. Tolerance is ± 0.25 mm unless otherwise specified.
- 3. Specifications are subject to change without notice.





Recommended soldering conditions (Lead frame type)

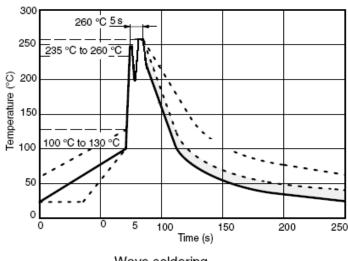
- Not to apply high temperature exceeding the maximum storage temperature to the epoxy resin.
- Not to apply any force to the epoxy resin at high temperature.
- Soldering process.
 - 1) The distance between holes should be the same as that of between terminal leads of the component to avoid any stress during the soldering process.
 - Also, lead forming should be done before soldering process not to apply stress to the inside of the epoxy resin.
 - 2) Not apply any stress to the component during the soldering process.

Wave soldering

1) Following soldering Bar & Wire recommended.

Melting temperature : 245 ~ 260°C

Composition: Pb-Free



Wave soldering

Manual Soldering

- 1) Use the Pb-Free solder or the solder containing silver.
- 2) Soldering iron below 320°C within 3 seconds.